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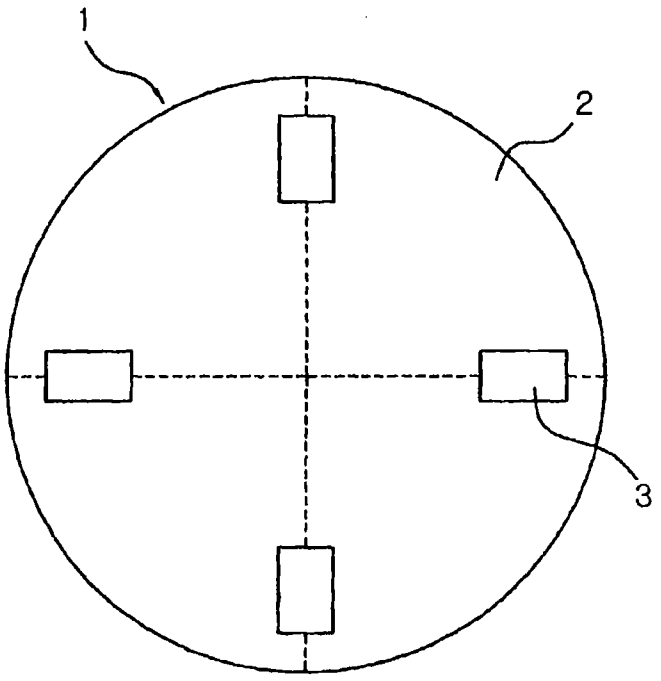
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(54) Title: POLISHING PAD HAVING MULTI-WINDOWS



(57) Abstract: A polishing pad of the invention enables the polished quantity of a wafer to be monitored rapidly and precisely in Chemical Mechanical Polishing. A plurality of transparent windows are introduced enabling the polished quantity of the wafer to be controlled more rapidly and precisely than in a conventional single transparent window structure. The transparent windows and the remaining portion of the pad (e.g., a polishing section) are integrally made of the same material so that the polishing pad of the invention enables a precise CMP process and achieve excellent structural endurance superior to a conventional pad of a single transparent window inserted therein.

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